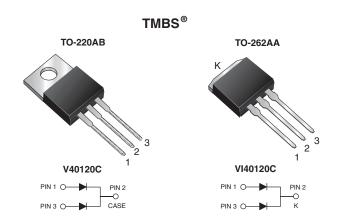
Vishay General Semiconductor

Dual High Voltage Trench MOS Barrier Schottky Rectifier

Ultra Low $V_F = 0.43$ V at $I_F = 5$ A



PRIMARY CHARACTERISTICS						
I _{F(AV)}	2 x 20 A					
V _{RRM}	120 V					
I _{FSM}	250 A					
V_F at $I_F = 20$ A	0.63 V					
T _J max.	150 °C					
Package	TO-220AB, TO-262AA					
Diode variation	Common cathode					

FEATURES

- Trench MOS Schottky technology
- Low forward voltage drop, low power losses
- · High efficiency operation
- Solder dip 275 °C max. 10 s, per JESD 22-B106
- AEC-Q101 qualified
- Material categorization: For definitions of compliance please see www.vishay.com/doc?99912

TYPICAL APPLICATIONS

For use in high frequency DC/DC converters, switching power supplies, freewheeling diodes, OR-ing diode, and reverse battery protection.

MECHANICAL DATA

Case: TO-220AB and TO-262AA

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

Base P/NHM3 - halogen-free, RoHS-compliant, and AEC-Q101 qualified

Terminals: Matte tin plated leads. solderable per J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test, HM3 suffix meets JESD 201 class 2 whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs max.

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)						
PARAMETER		SYMBOL	V40120C	VI40120C	UNIT	
Max. repetitive peak reverse voltage		V _{RRM}	120		V	
Max. average forward rectified current (fig. 1)	per device	I _{F(AV)}	40		A	
	per diode		20			
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode		I _{FSM}	250		А	
Voltage rate of change (rated V _R)		dV/dt	10 000		V/µs	
Operating junction and storage temperature range		T _J , T _{STG}	- 40 tc	+ 150	°C	

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HALOGEN

FREE





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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT	
Instantaneous forward voltage per diode	$I_F = 5 A$	T _A = 25 °C	- V _F (1)	0.50	-		
	I _F = 10 A			0.60	-	V	
	I _F = 20 A			0.78	0.88		
	$I_F = 5 A$	T _A = 125 °C		0.43	-		
	I _F = 10 A			0.53	-		
	I _F = 20 A			0.63	0.71		
Reverse current per diode	V _R = 90 V	T _A = 25 °C	I _R (2)	19	-	μA	
		T _A = 125 °C		10	-	mA	
	$V_{\rm P} = 120 V$	T _A = 25 °C		-	500	μA	
		T _A = 125 °C		22	45	mA	

Notes

⁽¹⁾ Pulse test: 300 µs pulse width, 1 % duty cycle

⁽²⁾ Pulse test: Pulse width \leq 40 ms

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	V40120C	VI40120C	UNIT	
Typical thermal resistance per diode	$R_{ ext{ heta}JC}$	1.8		°C/W	

ORDERING INFORMATION (Example)							
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
TO-220AB	V40120C-M3/4W	1.88	4W	50/tube	Tube		
TO-262AA	VI40120C-M3/4W	1.45	4W	50/tube	Tube		
TO-220AB	V40120CHM3/4W (1)	1.88	4W	50/tube	Tube		
TO-262AA	VI40120CHM3/4W (1)	1.45	4W	50/tube	Tube		

Note

⁽¹⁾ AEC-Q101 qualified

RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)

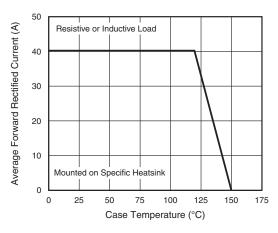


Fig. 1 - Maximum Forward Current Derating Curve

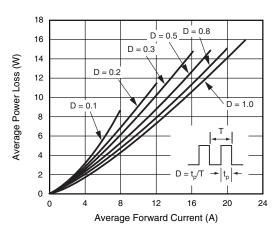


Fig. 2 - Forward Power Loss Characteristics Per Diode

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V40120C, VI40120C

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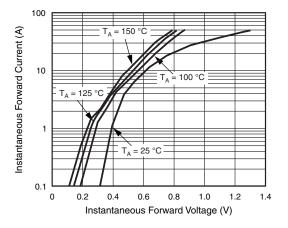


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

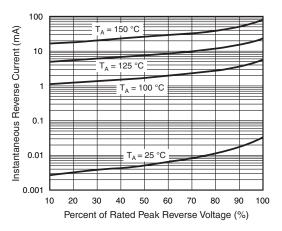


Fig. 4 - Typical Reverse Characteristics Per Diode

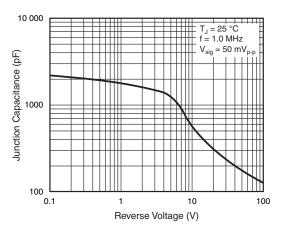


Fig. 5 - Typical Junction Capacitance Per Diode

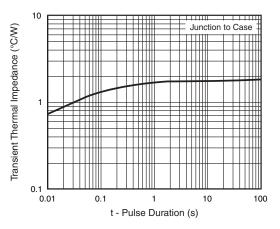


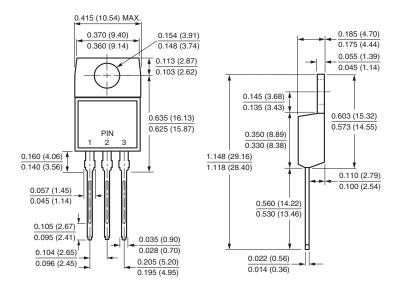
Fig. 6 - Typical Transient Thermal Impedance Per Diode



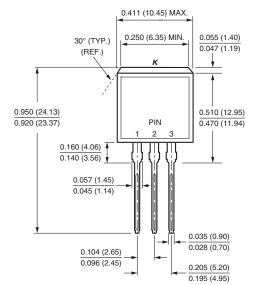


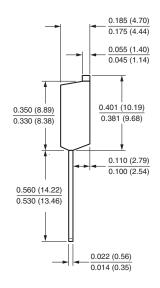
PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

TO-220AB



TO-262AA







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